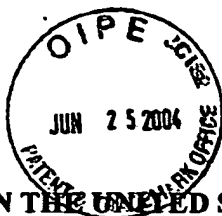


MICRON.225C1



Fee only

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant : Zhu et al.  
Appl. No. : 10/804,584  
Filed : March 16, 2004  
For : MAGNETO-RESISTIVE  
MEMORY CELL STRUCTURES  
WITH IMPROVED  
SELECTIVITY  
Examiner : Unknown

**PRELIMINARY AMENDMENT**

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Dear Sir:

Prior to examination on the merits, please amend the subject application as indicated below.

Amendments to the Claims are reflected in the listing of claims which begins on page 2 of this paper.

Remarks/Arguments begin on page 7 of this paper.

02/15/2005 CPARIS 00000001 111410 10804584

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